2.1± 0.1

Unit: mm

TOSHIBA Field Effect Transistor Silicon N Channel MOS Type

SSM3K7002FU

High Speed Switching Applications Analog Switch Applications

Small package

• Low ON resistance : $R_{on} = 3.3 \Omega \text{ (max)} (@V_{GS} = 4.5 \text{ V})$

: $R_{\mbox{on}} = 3.2~\Omega$ (max) (@V_{\mbox{GS}} = 5~V)

: $R_{on} = 3.0 \Omega \text{ (max) } (@V_{GS} = 10 \text{ V})$

Absolute Maximum Ratings (Ta = 25°C)

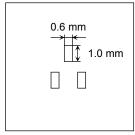
Characteristics		Symbol	Rating	Unit	
Drain-Source voltage		V_{DS}	60	V	
Gate-Source voltage		V_{GSS}	± 20	V	
Drain current	DC	I _D	200	mA	
	Pulse	I _{DP}	800		
Drain power dissipation (Ta = 25°C)		P _D (Note 1)	150	mW	
Channel temperature		T _{ch}	150	°C	
Storage temperature range		T _{stg}	−55 ~ 150	°C	

Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

Note 1: mounted on FR4 board

 $(25.4 \text{ mm} \times 25.4 \text{ mm} \times 1.6 \text{ t}, \text{ Cu Pad: } 0.6 \text{mm}^2 \times 3)$

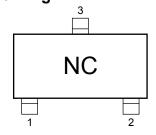


1.25 ± 0.1 1.25 ± 0.1 1.00 +

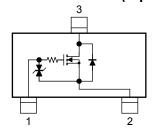
2-2E1E

TOSHIBA

Marking



Equivalent Circuit (top view)



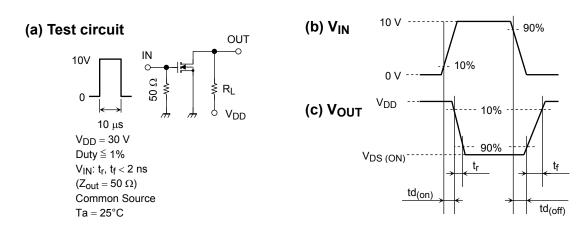
Handling Precaution

When handling individual devices (which are not yet mounting on a circuit board), be sure that the environment is protected against electrostatic electricity. Operators should wear anti-static clothing, and containers and other objects that come into direct contact with devices should be made of anti-static materials.

Electrical Characteristics (Ta = 25°C)

Characteristics		Symbol	Test Condition	Min	Тур	Max	Unit
Gate leakage current		I _{GSS}	$V_{GS} = \pm 20 \text{ V}, V_{DS} = 0$	_	_	± 10	μА
Drain-Source breakdown voltage		V (BR) DSS	$I_D = 0.1 \text{ mA}, V_{GS} = 0$	60	_	_	V
Drain cut-off current		I _{DSS}	V _{DS} = 60 V, V _{GS} = 0	_	_	1	μА
Gate threshold vol	tage	V _{th}	$V_{DS} = 10 \text{ V}, I_D = 0.25 \text{ mA}$	1.0	_	2.5	V
Forward transfer a	dmittance	Y _{fs}	V _{DS} = 10 V, I _D = 200 mA	170	_	_	mS
Drain-Source ON resistance		R _{DS} (ON)	$I_D = 500 \text{ mA}, V_{GS} = 10 \text{ V}$	_	2.0	3.0	Ω
			I _D = 100 mA, V _{GS} = 5 V	_	2.1	3.2	
			I _D = 100 mA, V _{GS} = 4.5 V	_	2.2	3.3	
Input capacitance		C _{iss}	V _{DS} = 25 V, V _{GS} = 0, f = 1 MHz	_	17	_	pF
Reverse transfer capacitance		C _{rss}		_	1.4	_	pF
Output capacitance		Coss		_	5.8	_	pF
Switching time	Turn-on delay time	td _(on)	V _{DD} = 30V, I _D = 200 mA,	_	2.4	4.0	ns
	Turn-off delay time	td _(off)	V _{GS} = 0 ~ 10V	_	26	40	

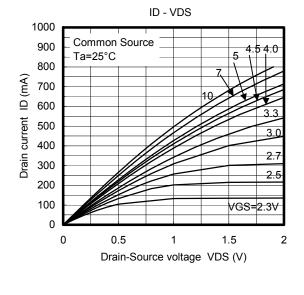
Switching Time Test Circuit

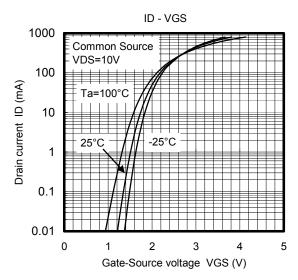


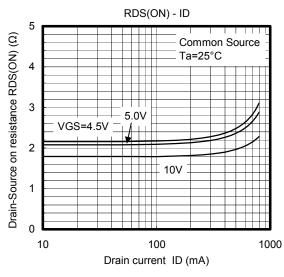
Precaution

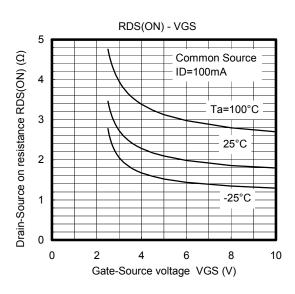
 V_{th} can be expressed as voltage between gate and source when low operating current value is I_D = 250 μ A for this product. For normal switching operation, V_{GS} (on) requires higher voltage than V_{th} and V_{GS} (off) requires lower voltage than V_{th} . (Relationship can be established as follows: V_{GS} (off) < V_{th} < V_{GS} (on))

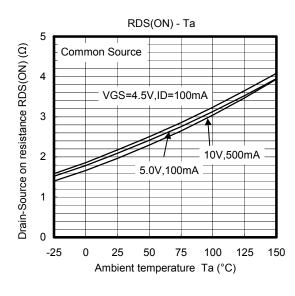
Please take this into consideration for using the device.

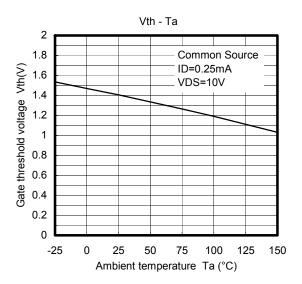


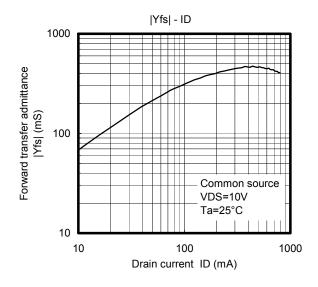


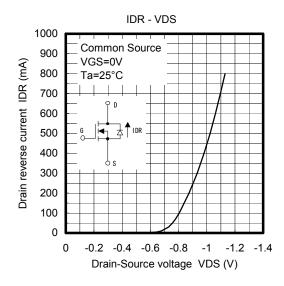


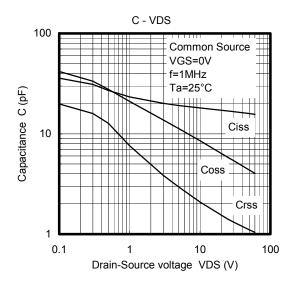


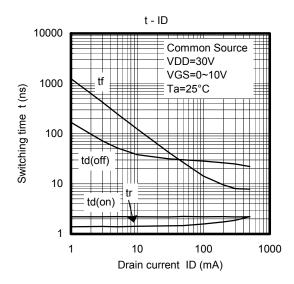


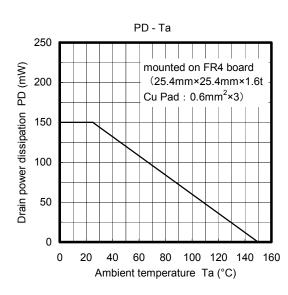












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20070701-EN GENERAL

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